

-55V Dual P-Channel HEXFET Power MOSFET in a SO-8 package; Similar to IRF7342TR with Lead Free Packaging on Tape and Reel

Manufacturers	Infineon Technologies Corporation
Package/Case	SOP-8
Product Type	Transistors
RoHS	Green
Lifecycle	



Images are for reference only

Please submit RFQ for IRF7342TRPBF or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

>>

Fifth Generation HEXFETs from International Rectifier utilize advanced processing techniques to achieve extremely low on-resistance per silicon area. This benefit, combined with the fast switching speed and ruggedized device design that HEXFET Power MOSFETs are well known for, provides the designer with an extremely efficient and reliable device for use in a wide variety of applications.

Generation V Technology
 Ultra Low On-Resistance
 Dual P-Channel Mosfet
 Surface Mount
 Available in Tape & Reel
 Dynamic dv/dt Rating
 Fast Switching

Features

RoHS Compliant

Low RDS(on)

Dynamic dv/dt Rating

Fast Switching

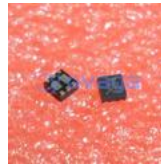
Dual P-Channel MOSFET

Related Products



[IRLTS6342TRPBF](#)

Infineon Technologies Corporation
TSOP-6



[IRLHS6376TRPBF](#)

Infineon Technologies Corporation
PQFN2x2DD



[IRF9310PBF](#)

Infineon Technologies Corporation
SOIC-8



[IRFH9310TRPBF](#)

Infineon Technologies Corporation
PQFN-8



[IRF9358TRPBF](#)

Infineon Technologies Corporation
SOP-8



[IRFB7430PBF](#)

Infineon Technologies Corporation
TO-220



[IRFB3307ZPBF](#)

Infineon Technologies Corporation
TO-220AB



[IRF7351TRPBF](#)

Infineon Technologies Corporation
SOIC-8